



SANYO Semiconductors

## DATA SHEET

# LA2000 — Monolithic Linear IC Audio Level Sensor

## Overview

The LA2000 is an IC for detecting interprogram spaces to pick out the starting point of a program immediately preceding or following a musical program recorded on tape, and to detect end of tape.

## Used in

- Radio-cassette recorders
- Cassette decks
- Car stereos

## Applications

- Detection of spaces between programs recorded on tape
- Detection of end of tape
- Other

## Features

- Has transistors capable of driving plungers with maximum 600mA, and a protective diode to prevent induced reverse voltages.
- Can provide designated time delays by externally connected capacitors and resistors.
- Has a comparator with stable hysteresis to handle variations in power supply voltage.
- Detects unrecorded portions of tape.

## Specifications

**Maximum Ratings** at  $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	$V_{CC\text{ max}}$		15	V
Flow-in current	$I_{\text{g max}}$		600	mA
Allowable power dissipation	$P_{\text{d max}}$		540	mW
Operating temperature	$T_{\text{opr}}$		-20 to +75	$^\circ\text{C}$
Storage temperature	$T_{\text{stg}}$		-40 to +125	$^\circ\text{C}$

Note : 1. The voltage at pin 8 must not exceed the supply voltage at pin 9.

2. The maximum current flowing into pin 8 should be no greater than 0.5mA.

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**SANYO Semiconductor Co., Ltd.**

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## LA2000

### Operating Conditions at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Operating voltage range	$V_{CC\text{ op}}$		3.5 to 14	V

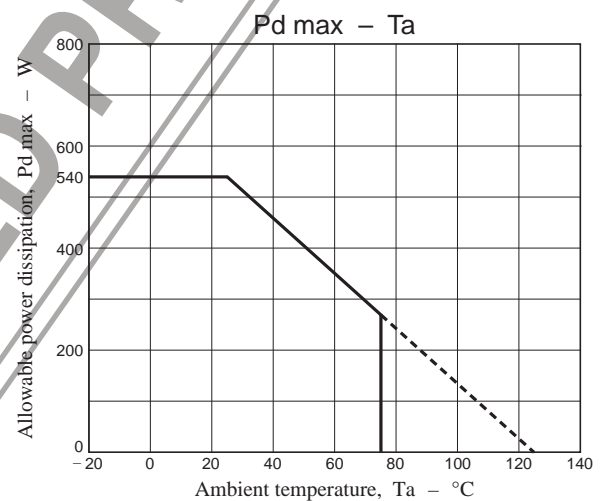
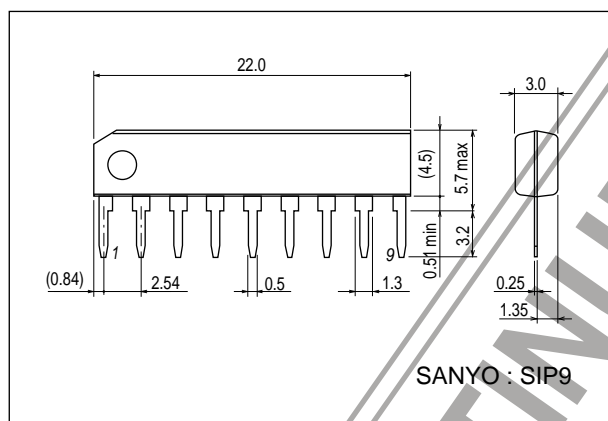
### Electrical Characteristics at $T_a = 25^\circ\text{C}$ , $V_{CC} = 9.0\text{V}$ , $f = 1\text{kHz}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Circuit current	$I_{CC}$	$f = 1\text{kHz}$ , $V_{IN} = -45\text{dB}$		6	12	mA
Output transistor saturating voltage	$V_{CE\text{ (sat)}}$	$I_O = 600\text{mA}$		1.5	2.5	V
Output diode forward voltage	$V_F$	$I_F = 600\text{mA}$		1.5	2.0	V
Output-off level in input equivalent	$V_{IN}$	$f = 1\text{kHz}$	-43	-50	-54	dBm
Comparator-on level	$V_{TH-H}$		3.0	3.5	4.0	V
Comparator-off level	$V_{TH-L}$		1.8	2.2	2.6	V
Pin 8 high level	$V_8\text{ pin}$		0.45	0.55		V
Output transistor leakage current	$I_{L-TR}$				100	$\mu\text{A}$
Output diode leakage current	$I_{L-Di}$				100	$\mu\text{A}$

### Package Dimensions

unit : mm (typ)

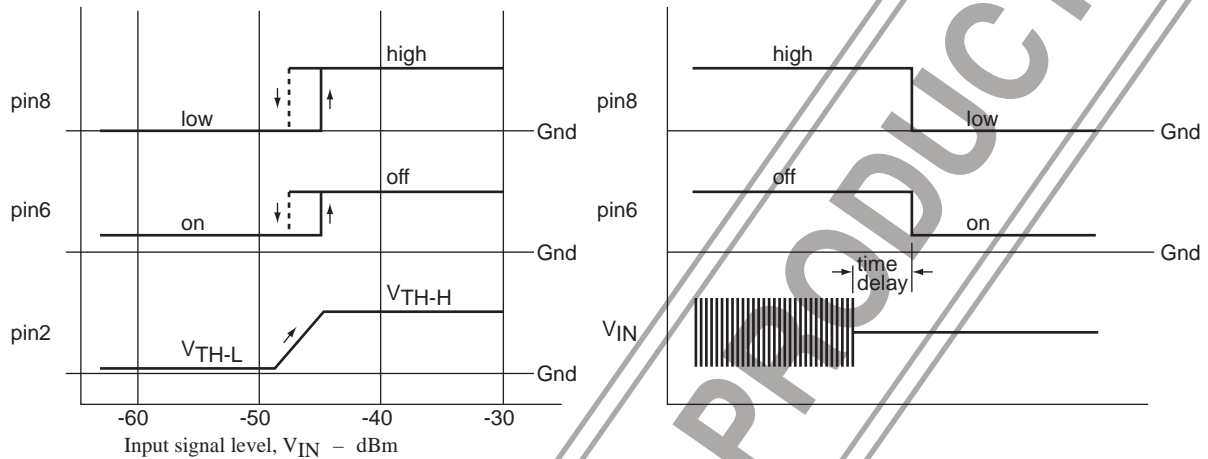
3017D



### 1. Description of external parts

- C1 • Input coupling capacitor : 0.47 to 2.2μF recommended.
- C2 • NF capacitor : Capacitance is reduced, so the off level in input equivalent becomes lower in the bass frequency range. We recommend 1 to 10μF.
- C3, R1 • For designation of time delays : Any time delay can be obtained by adequate choice of C3 and R1. We recommend 150k to 500kΩ for R1.
- C4, R3 • Power supply ripple filter
- R2 • Bias resistor : For diode when pin 8 is used to drive external transistors. A 1kΩ resistor is recommen.

### 2. Individual pins and their operations



As shown above, when input level is raised and the pin 2 voltage reaches the  $V_{TH-H}$  level of the comparator, pins 6 and 8 turn over. ( $V_{IN} = -45\text{dBm}$ ).

- Pin 6 is for driving plungers, When it is on the “L” side, pin 6 turns on and can draw current up to 600mA maximum (restricted by duty-cycle chart). It is not to be on continuously for more than 3 seconds.
- Pin 7 is a diode that prevents reverse voltages induced when the plunger is turned off from on.
- Pin 8 functions in phase with pin 6 and can drive external transistors (such as for MUTE ).

### 3. Time delays and obtaining CRs

When input signals that have been applied at a level not less than  $-45\text{dBm}$  are removed, discharging occurs through the CR connected at pin 2, lowering pin 2 potential. A time delay is provided before the hysteresis comparator turns over.

$$\frac{E1}{E0} = -\frac{t}{\tau}$$

$E0$  : Initial voltage  
 $E1$  : Threshold voltage  
 $\tau$  : Time constant

Accordingly,

$$t = -\tau \ln \frac{E1}{E0}$$

$E1/E0$ , within the IC, is 0.26. A desired time is obtained by an appropriate choice of  $\tau$  ( $\tau = C3R1$ ). Therefore, the time delay is obtained by the following formula :

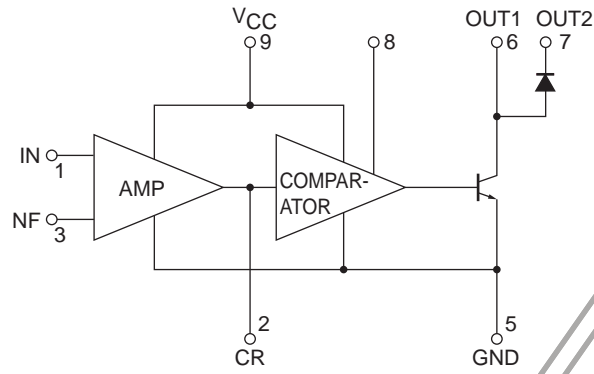
$$t = 1.34 \times C3R1 \text{ (sec)}$$

We recommend 150k to 500kΩ for R when determining CR.

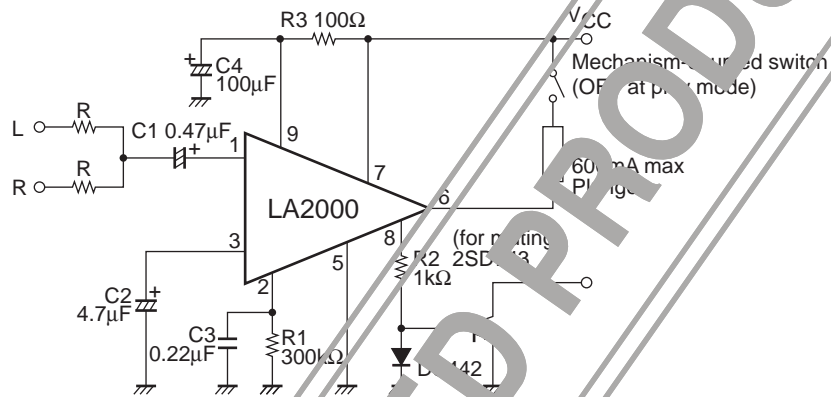


# LA2000

## Block Diagram

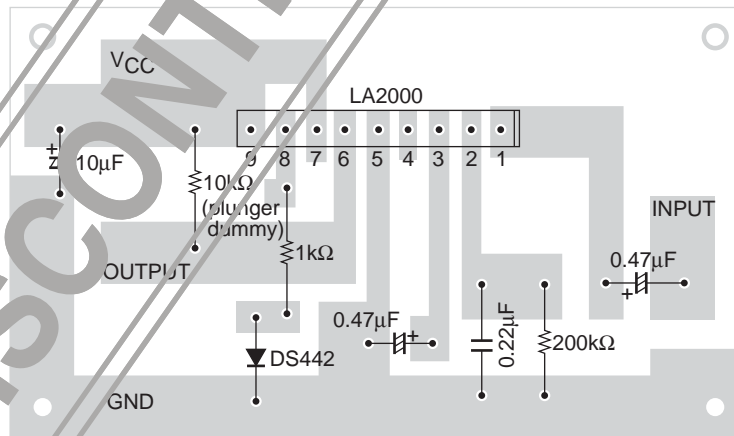


## Sample Application Circuit 1

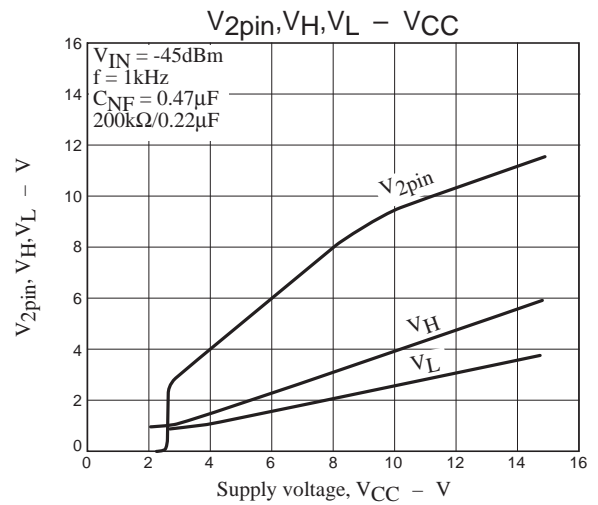
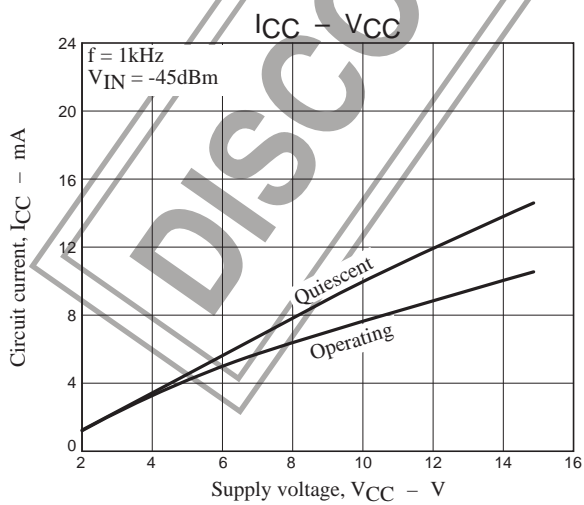
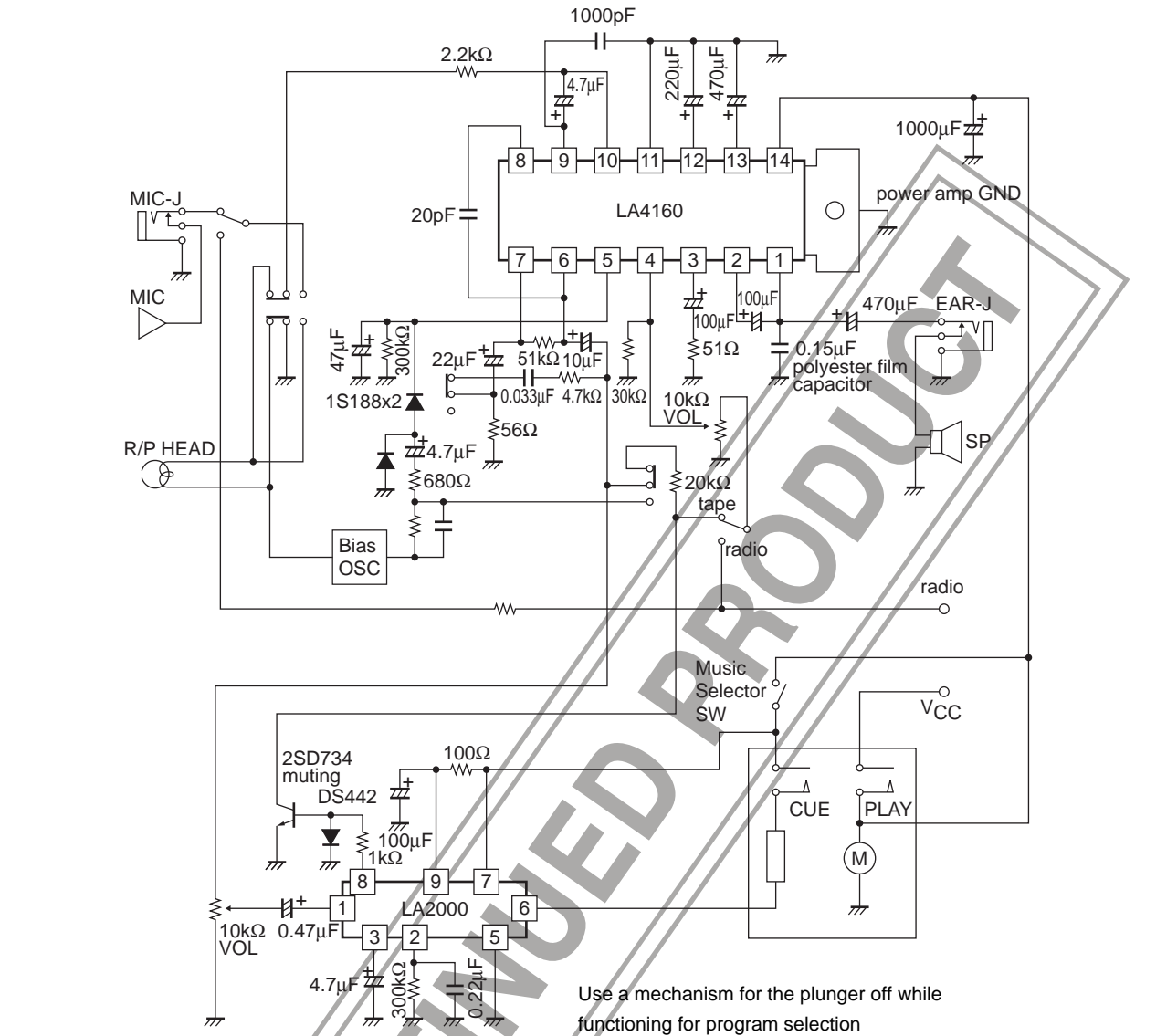


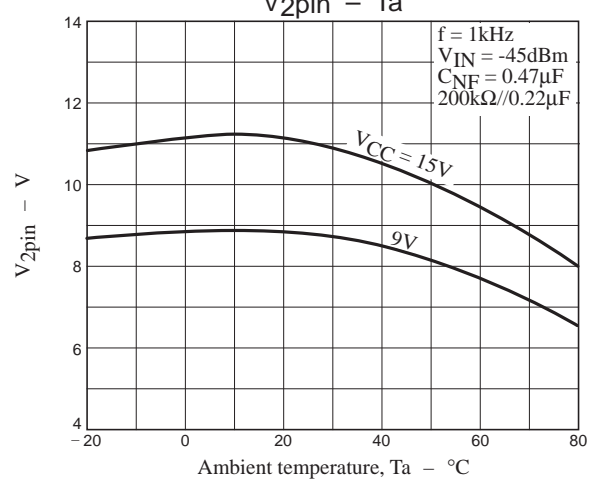
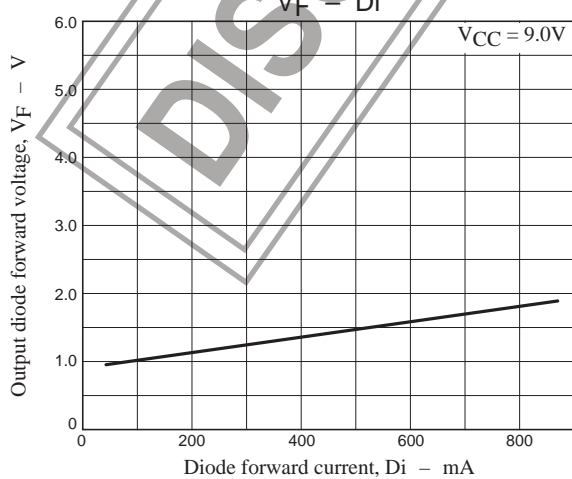
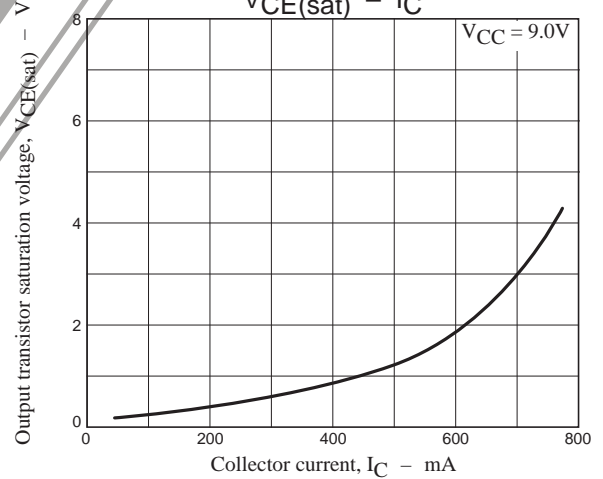
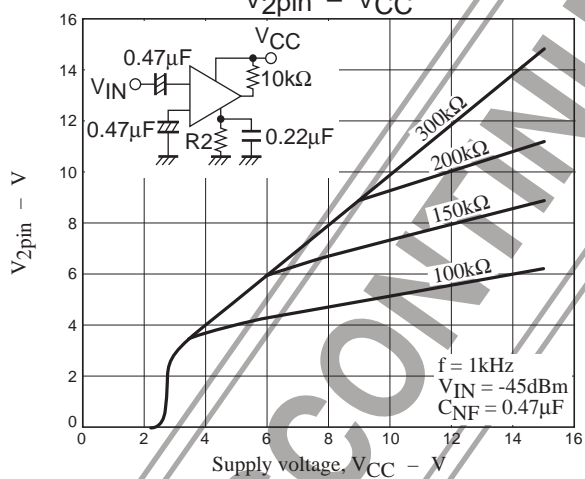
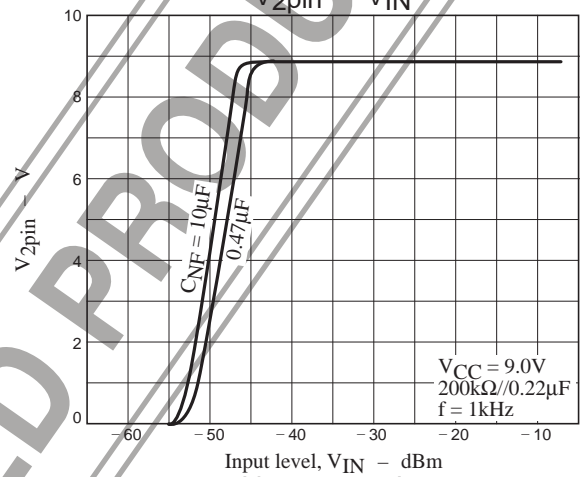
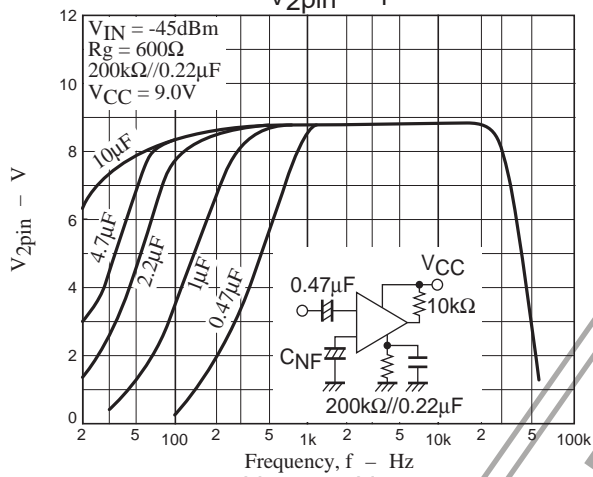
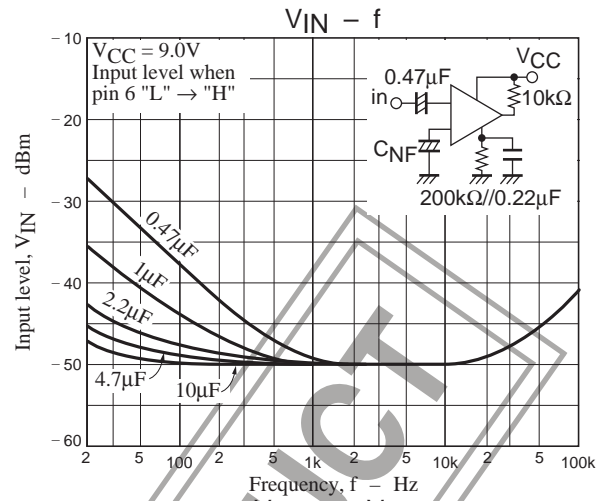
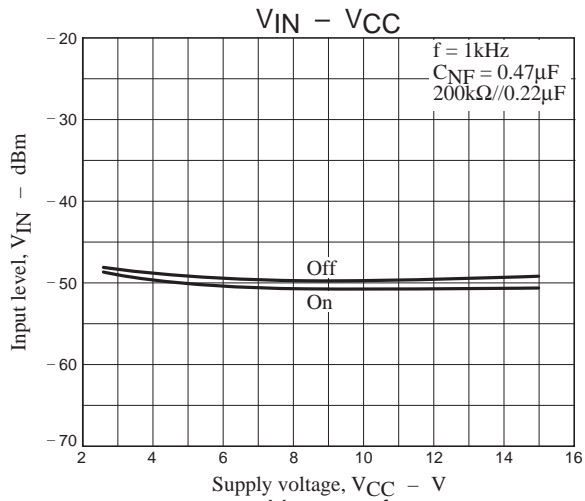
Pin 4 is unconnected but is not to be used for GND or an interconnection terminal.

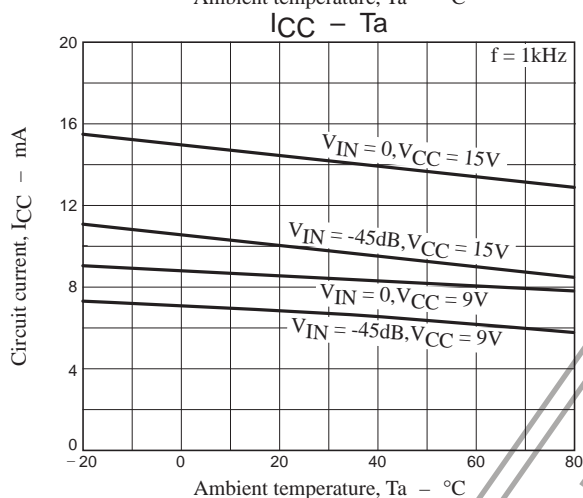
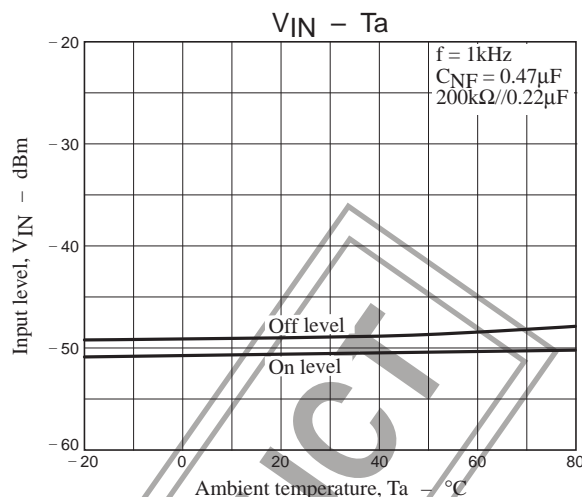
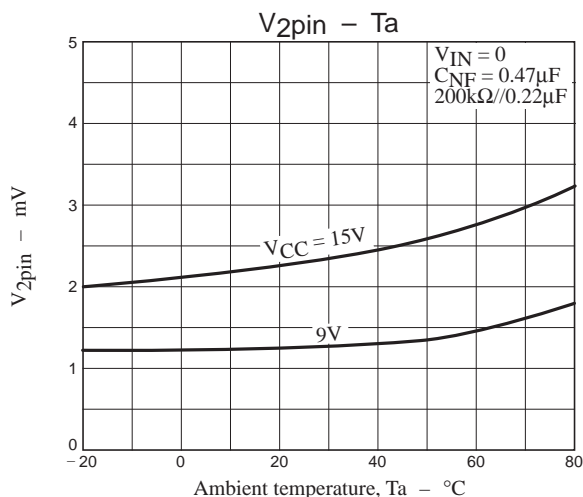
## Sample Printed Pattern (copper foil side)



# Sample Application Circuit 2







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